



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL10A105KA8NNNC

Product : Multi-layer Ceramic Capacitor
Descriptiont : CAP, 1μF, 25V, ±10%, X5R, 0603

A. Samsung Part Number

<u>CL</u> <u>10</u> <u>A</u> <u>105</u> <u>K</u> <u>A</u> <u>8</u> <u>N</u> <u>N</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ 8 ⑨ ⑩ ⑪

① Series	Samsung Mu	Samsung Multi-layer Ceramic Capacitor				
② Size	0603 (inch	code) L: 1.6	3 ± 0.1 mm	W: 0.8 ± 0.1	mm	
③ Dielect	ric X5R	8	Inner electrode	Ni		
4 Capaci	tance 1 μF		Termination	Cu		
⑤ Capaci	tance ±10 %		Plating	Sn 100%	(Pb Free)	
toleran	ce	9	Product	Normal		
6 Rated	Voltage 25 V	10	Special	Reserved for	future use	
7 Thickn	ess 0.8 ± 0.1	mm 🕦	Packaging	Cardboard T	ype, 7" reel	

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition		
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms		
Tan δ (DF)	0.1 max.			
Insulation	10,000Mohm or 500Mohm⋅μF	Rated Voltage 60~120 sec.		
Resistance	Whichever is Smaller			
Appearance No abnormal exterior appearance		Microscope (×10)		
Withstanding	No dielectric breakdown or	250% of the rated voltage		
Voltage	mechanical breakdown			
Temperature	X5R			
Characteristics	(From -55 ℃ to 85 ℃, Capacitance change should be within ±15%)			
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.		
of Termination	terminal electrode			
Bending Strength	Capacitance change : within ±12.5%	Bending to the limit (1mm)		
		with 1.0mm/sec.		
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder		
	is to be soldered newly	245±5℃, 3±0.3sec.		
		(preheating : 80~120 ℃ for 10~30sec.)		
Resistance to	Capacitance change : within ±7.5%	Solder pot : 270±5℃, 10±1sec.		
Soldering heat	Tan δ, IR : initial spec.			

	Performance	Test condition	
Vibration Test	Capacitance change: within ±5%	Amplitude: 1.5mm	
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)	
		2hours × 3 direction (x, y, z)	
Moisture	Capacitance change: within ±12.5	% With rated voltage	
Resistance	Tan δ: 0.125 max	40±2℃, 90~95%RH, 500+12/-0hrs	
	IR : 12.5MΩ·μF or Over		
High Temperature	Capacitance change : within ±12.5	% With 150% of the rated voltage	
Resistance	Tan δ: 0.125 max	Max. operating temperature	
	IR : 25MΩ·μF or Over		
		1000+48/-0hrs	
Temperature	Capacitance change: within ±7.5%	1 cycle condition	
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25 °C	
		→ Max. operating temperature → 25°C	
		5 cycle test	

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C , 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.